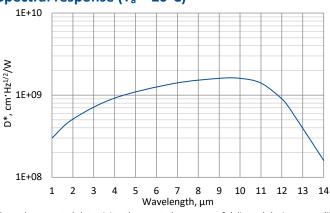


### PCI-3TE-12-1×1-T08-wZnSeAR-36

# $2-14~\mu m$ HgCdTe three-stage thermoelectrically cooled, optically immersed photoconductive detector

**PCI-3TE-12-1×1-T08-wZnSeAR-36** is a three-stage thermoelectrically cooled IR photoconductor, based on sophisticated HgCdTe heterostructure for the best performance and stability. The device is optimized for the maximum performance at 12 µm. Detector element is monolithically integrated with hyperhemispherical GaAs microlens in order to improve performance of the device. Photoconductive detector should operate in optimum bias voltage and current readout mode. Performance at low frequencies is reduced due to 1/f noise. 3° wedged zinc selenide anti-reflection coated (wZnSeAR) window prevents unwanted interference effects.

### Spectral response (T<sub>a</sub> = 20°C)





Exemplary spectral detectivity, the spectral response of delivered devices may differ.

### Specification ( $T_a = 20$ °C)

Parameter	Detector type
	PCI-3TE-12-1×1-TO8-wZnSeAR-36
Active element material	epitaxial HgCdTe heterostructure
Cut-on wavelength $\lambda_{\text{cut-on}}$ (10%), $\mu$ m	≤2.0
Peak wavelength λ <sub>peak</sub> , μm	10.0±0.2
Optimum wavelength λ <sub>opt</sub> , μm	12.0
Cut-off wavelength $\lambda_{\text{cut-off}}$ (10%), $\mu$ m	14.0±0.2
Detectivity D*( $\lambda_{peak}$ ), cm·Hz <sup>1/2</sup> /W	≥1.6×10 <sup>9</sup>
Detectivity D*( $\lambda_{opt}$ ), cm·Hz <sup>1/2</sup> /W	≥9.0×10 <sup>8</sup>
Current responsivity R <sub>i</sub> (λ <sub>peak</sub> ), A/W	≥0.11
Current responsivity $R_i(\lambda_{opt})$ , A/W	≥0.07
Time constant τ, ns	≤5
Resistance R, $\Omega$	≤300
Bias voltage V <sub>b</sub> , V	≤1.8
1/f noise corner frequency fc, kHz	≤20
Active element temperature T <sub>det</sub> , K	~210
Optical area Ao, mm×mm	1×1
Package	TO8
Acceptance angle Φ	~36°
Window	wZnSeAR

#### **Features**

- Wide spectral range from 1 to 14 μm
  - High responsivity
- Large dynamic range
- Excellent long term stability and reliability
- Quantity discounted price
- Fast delivery

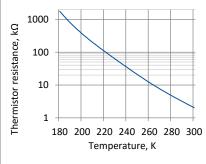
#### **Applications**

FTIR spectroscopy and spectrometry

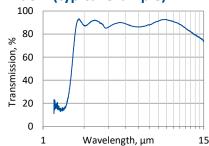
## Three-stage thermoelectric cooler parameters

Jaranieters	
Parameter	Value
T <sub>det</sub> , K	~210
V <sub>max</sub> , V	3.6
I <sub>max</sub> , A	0.45
Omay W	0.27

### Thermistor characteristics

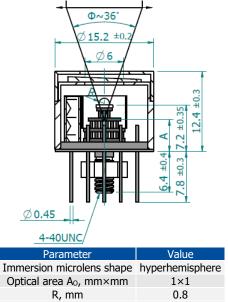


### Spectral transmission of wZnSeAR window (typical example)







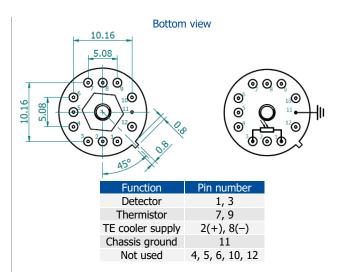




 $\Phi$  – acceptance angle

R – hyperhemisphere microlens radius

A – distance from the bottom of the 3TE-TO8 header to the focal plane



### **Precautions for use and storage**

- Heatsink with thermal resistance of ~2 K/W is necessary to dissipate heat generated by 3TE cooler.
- Operation in 10% to 80% humidity and -20°C to 30°C ambient temperature.
- Beam power limitations for optically immersed detector:
  - irradiance with CW or single pulse longer than 1 µs irradiance on the apparent optical active area must not exceed 2.5 W/cm<sup>2</sup>,
  - irradiance of the pulse shorter than 1 µs must not exceed 10 kW/cm<sup>2</sup>.
- Storage in dark place with 10% to 90% humidity and -20°C to 50°C ambient temperature.

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